# BGS12AL7-4 SPDT RF Switch

## Small Signal Discretes



Never stop thinking

Edition 2008-05-26

Published by Infineon Technologies AG 81726 München, Germany © Infineon Technologies AG 2008. All Rights Reserved.

#### Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie"). With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

#### Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office (www.infineon.com).

#### Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.



Previous Version: 2008-02-07, V1.0					
Page	Subjects (major changes since last revision)				
7	Electrical Specifications				
8	Measurement Results				
9	Application Board				

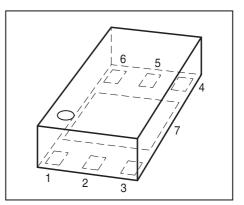


### BGS12AL7-4

#### Features

- Low insertion loss
- High port-to-port-isolation
- Low harmonic generation
- On-chip control logic
- · High ESD robustness
- · No external components required
- · General purpose switch for applications up to 3 GHz
- Small leadless package TSLP-7-4
- · Lead and halogen free package (RoHS and WEEE compliant)



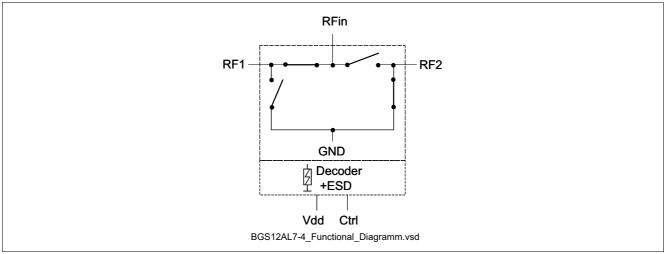


#### Description

The BGS12AL7-4 General Purpose RF MOS switch is designed to cover a broad range of applications from 0.1 to 3 GHz. The symmetric design of its single pole double throw configuration, as shown in **Figure 1** offers high design flexibility. This single supply chip integrates on-chip CMOS logic driven by a simple, single-pin CMOS or TTL compatible control input signal. The 0.1 dB compression point exceeds the switch's maximum input power level of 21 dBm, resulting in linear performance at all signal levels. The RF switch has a very low insertion loss of 0.35 dB in the 1 GHz and 0.65 dB in the 2 GHz range.

Unlike GaAs technology, external DC blocking capacitors at the RF ports are only required if DC voltage is applied externally.

The BGS12AL7-4 RF switch is manufactured in Infineon's patented MOS technology, offering the performance of GaAs with the economy and integration of conventional CMOS including the inherent higher ESD robustness.



#### Figure 1 Functional Diagram

Туре	Package	Marking	Chip
BGS12AL7-4	TSLP-7-4	12	M4781



#### Table 1 Maximum Ratings

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.	1	Test Condition
Storage temperature range	$T_{\rm stg}$	-65		150	°C	
DC Voltage at all pins to GND	V <sub>DC</sub>			5	V	
RF power max. at all RF ports	P <sub>IN</sub>			24	dBm	
ESD Capability		1		1		
Human Body- JEDEC JESD22-A114 Machine-Model JEDEC JESD22-A115	V <sub>ESD</sub>			1000 250	V	

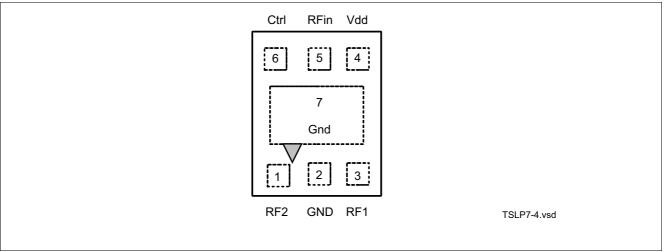
#### Table 2Operation Ranges

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.	-	<b>Test Condition</b>
Ambient temperature	T <sub>A</sub>	-30		85	°C	
RF Frequency	f	0.1		3	GHz	
Control voltage low	V <sub>CtrL</sub>	-0.3		0.3	V	
Control voltage high	V <sub>CtrlH</sub>	1.4		Vdd	V	
Supply voltage <sup>1)</sup>	V <sub>dd</sub>	2.4		2.8	V	
Current consumption Vdd Pin (over temperature)	I <sub>Vdd</sub>	80		350	μA	
Current Consumption Vctrl Pin	I <sub>Ctrl</sub>			30	μA	
Power Range	P <sub>in</sub>				dBm	
(VSWR ∞: 1))				15		
(VSWR 3: 1)				18		
(VSWR 1: 1)				21		

1) Supply voltage must be connected before Control Voltage



Table 3	Table 3 Pin description					
Pin	Name	Description				
1	RF2	RF Port 2 Out				
2	GND	Ground				
3	RF1	RF Port 1 Out				
4	Vdd	Supply Voltage				
5	RFIN	RF Port In				
6	CTRL	Control Pin				



#### Figure 2 Pin Configuration (top view)

#### Table 4 Truth Table

Ctrl 1	RF 1	RF 2
0	1	0
1	0	1



#### **Electrical Specifications**

- Termination port impedance:  $Z_0 = 50 \Omega$
- Temperature range: T = -30 °C...+85 °C
- Supply Voltage:  $V_{dd}$  = 2.8 V
- *P*<sub>in</sub> = 15 dBm
- Across operating range of control voltages:  $V_{\rm CtrH}$  = 1.4...2.8 V

#### Table 5 Electrical Characteristics

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
Insertion Loss	IL		0.4 <sup>1)</sup>		dB	f = 1  GHz TX,
			0.5 <sup>1)</sup>		dB	f = 2 GHz TX,
Return Loss	RL	15	22		dB	<i>f</i> = 1 GHz
		15	22		dB	<i>f</i> = 2 GHz
Isolation RFin - RF1	ISO <sub>RFin-RF1</sub>	20	32		dB	<i>f</i> = 1 GHz
		15	25		dB	<i>f</i> = 2 GHz
Isolation RFin - RF2	ISO <sub>RFin-RF2</sub>	20	32		dB	<i>f</i> = 1 GHz
		15	25		dB	<i>f</i> = 2 GHz
Isolation RF1 - RF2	ISO <sub>RF1-RF2</sub>	24	32		dB	<i>f</i> = 1 GHz
		15	25		dB	<i>f</i> = 2 GHz
Isolation RF ports - Vdd, Vctrl	ISO <sub>RF-DC</sub>	30	35		dB	<i>f</i> = 1 GHz
		20	35		dB	<i>f</i> = 2 GHz
Harmonic Generation up to 12.75 GHz	P <sub>Harm</sub>		-75	-50	dBm	<i>f</i> = 1 GHz
			-80	-50	dBm	<i>f</i> = 2 GHz
On Switching Time (10-90%) RF	t <sub>on</sub>			5	μs	<i>f</i> = 1 GHz
Off Switching Time (10-90%) RF	t <sub>off</sub>			5	μs	<i>f</i> = 1 GHz
Current Consumption at Vdd Pin	$I_{\rm dd}$		120		μA	
Input 0.1 dB compression	$P_{0.1 \mathrm{dB}}$	21			dBm	<i>f</i> = 1 GHz
$\frac{1}{1} \otimes T_{r} = 25 ^{\circ} \text{C}$	0.108					J

1)@*T*<sub>A</sub> = 25 °C



#### Measurement Results (@ T = 25°C)

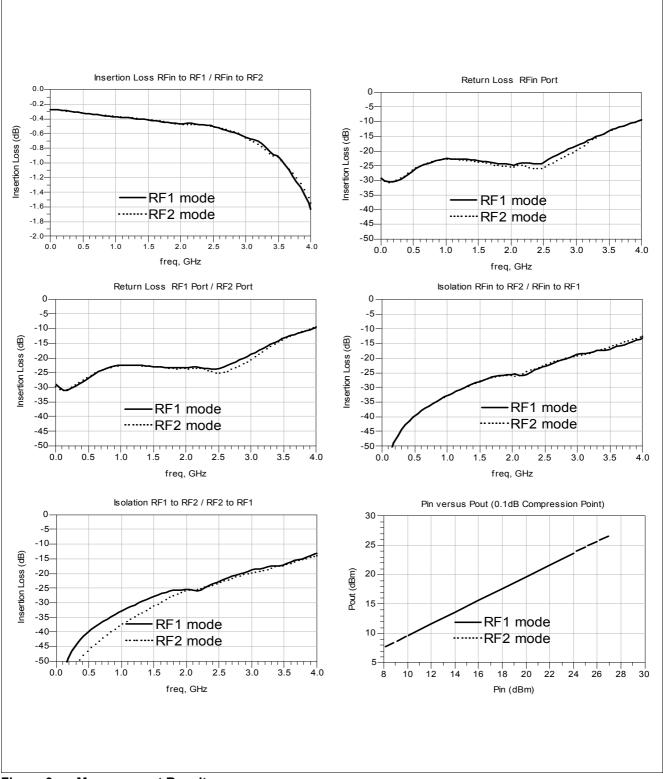
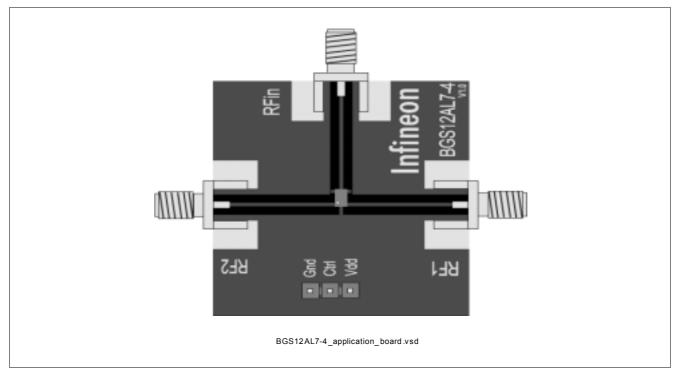
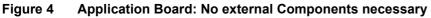


Figure 3 Measurement Results



#### **Application Board**





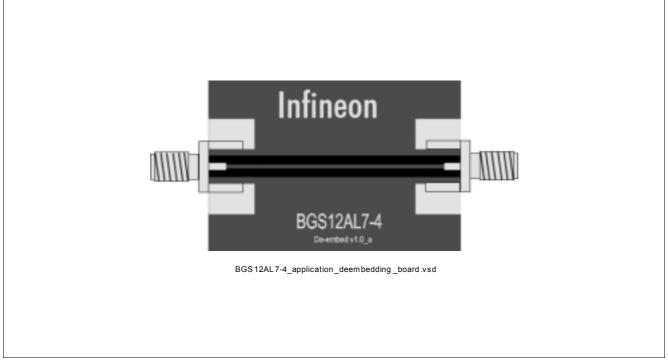
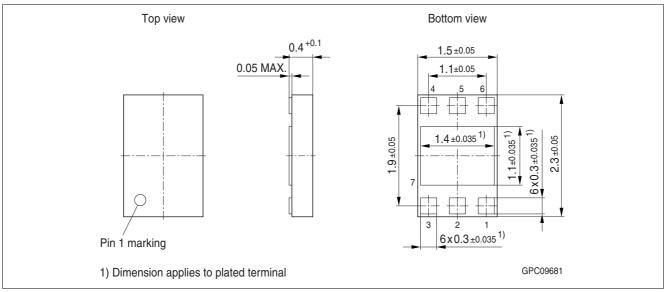


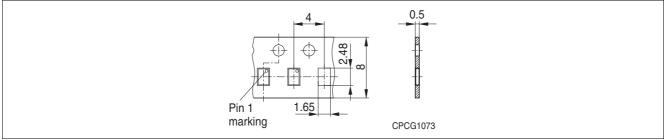
Figure 5 Application Deembedding Board



#### **Package Outlines**







#### Figure 7 Tape Info

Dimensions in mm

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": http://www.infineon.com/products.